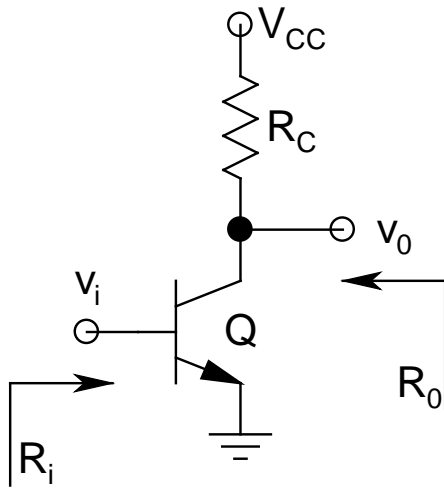
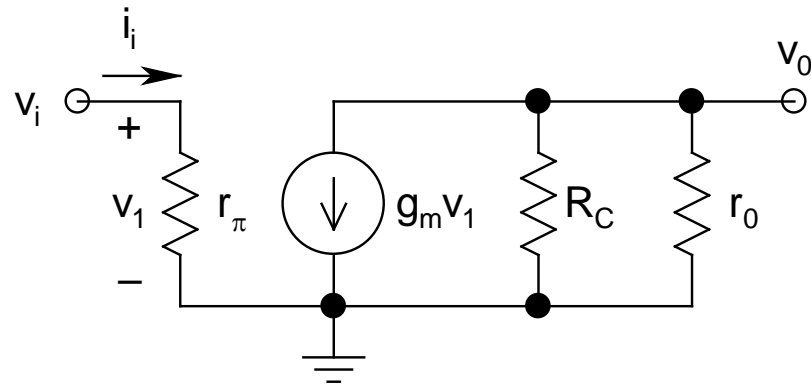


# Single-Stage Amplifiers

- **Common-Emitter (CE):**



ac Schematic



ac Low-Frequency Equivalent

➤ ***Biasing circuit not shown***

- By inspection, *Voltage Gain*:

$$A_v = \frac{v_o}{v_i} = \frac{-g_m v_1 (R_C \parallel r_o)}{v_i} = -g_m (R_C \parallel r_o)$$

- The *negative sign* in front implies *180° phase shift* between  $v_i$  and  $v_o$

- *$v_i$  and  $v_o$  are exactly out of phase*

- For *discrete circuits*, in general,  $R_C \ll r_o$

$$\Rightarrow A_v = -g_m R_C \approx -R_C/r_E \text{ (moderate to large)}$$

- On the other hand, if  $r_o \ll R_C$ :

$$A_v = -g_m r_o = 1/\eta = V_A/V_T \text{ (can be huge!)}$$

- *Theoretical maximum voltage gain of this circuit*

➤ ***Current Gain:***

$$A_i = i_c/i_b = \beta \text{ (*large*)}$$

➤ Thus, ***Power Gain:***

$$PG = A_v \times A_i \text{ (*very large*)}$$

➤ Therefore, this circuit is *designers' favorite!*

➤ Has primary use as *audio amplifiers*

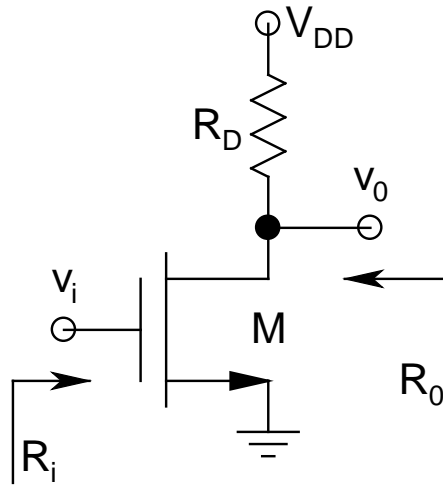
➤ ***Input Resistance:***

$$R_i = v_i/i_i = r_\pi \text{ (*decent*)}$$

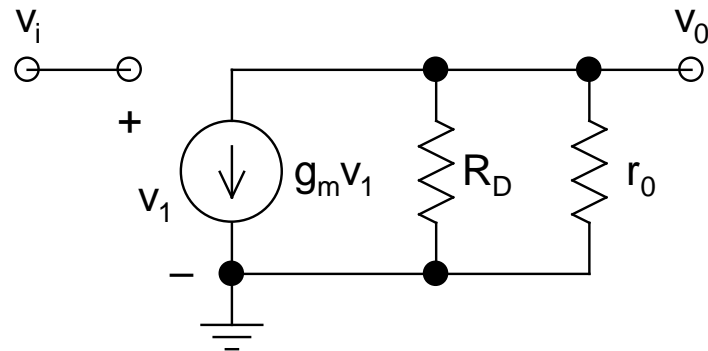
➤ ***Output Resistance:***

$$R_o = R_C || r_o$$

- **Common-Source (CS):**



ac Schematic



ac Low-Frequency Equivalent

- **Biasing circuit not shown**
- **Body at ground  $\Rightarrow$  No body effect**

- By inspection, ***Voltage Gain***:

$$A_v = \frac{v_o}{v_i} = \frac{-g_m v_1 (R_D \parallel r_o)}{v_i} = -g_m (R_D \parallel r_o)$$

- The ***negative sign*** in front implies ***180° phase shift*** between  $v_i$  and  $v_o$

- ***$v_i$  and  $v_o$  are exactly out of phase***

- For ***discrete circuits***, in general,  $R_D \ll r_o$

$$\Rightarrow A_v = -g_m R_D \text{ (*moderate*)}$$

- ***Input Resistance***:  $R_i \rightarrow \infty$

- ***Output Resistance***:  $R_o = R_D \parallel r_o$

- ***Note the remarkable similarity with CE stage***

➤ If  $R_D \gg r_0$ :

$$A_v = -g_m r_0 = -k_N V_{GT}/(\lambda I_D) = -2/[\lambda(\Delta V)]$$

(*assuming  $\lambda V_{DS} < 0.1$* )

➤ Thus, *for small  $\lambda$  and small  $\Delta V$ ,  $A_v$  can be large*

▪ Keep in mind that  $\Delta V(\min) = 3V_T$

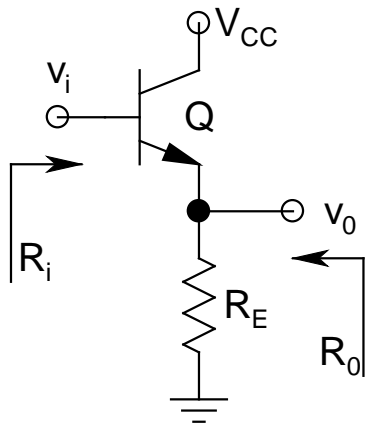
➤ Also,  $A_v \propto 1/\sqrt{I_D}$

$\Rightarrow$  *Lower  $I_D$ , higher  $A_v$*

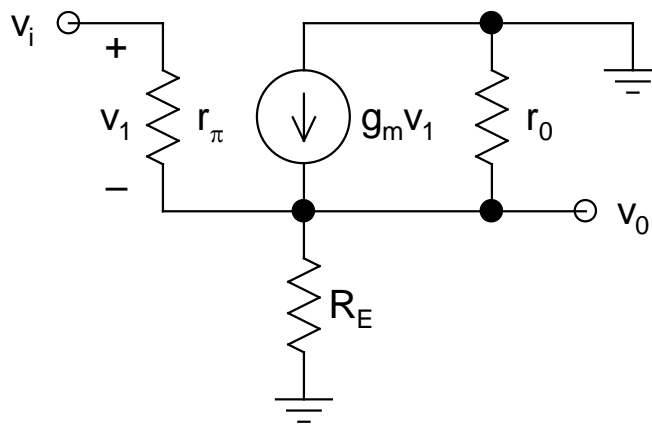
➤ *Recall*: For *CE stage*,  $A_v(\max)$  was *independent of  $I_C$* , and *dependent only on  $T$*

- **Common-Collector (CC):**

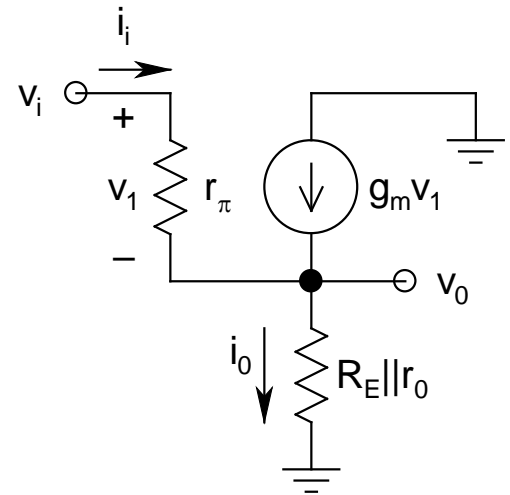
➤ Also known as **Emitter-Follower**



ac Schematic



ac Low-Frequency Equivalent



Simplified ac Low-Frequency Equivalent

➤ **Biasing circuit not shown**

➤ *Voltage Gain:*

$$\begin{aligned} A_v &= \frac{v_o}{v_i} = \frac{i_o (R_E \parallel r_o)}{v_i + v_o} = \frac{(\beta + 1) i_i (R_E \parallel r_o)}{i_i r_\pi + (\beta + 1) i_i (R_E \parallel r_o)} \\ &= \frac{(R_E \parallel r_o)}{r_\pi / (\beta + 1) + (R_E \parallel r_o)} = \frac{(R_E \parallel r_o)}{r_E + (R_E \parallel r_o)} \end{aligned}$$

➤ Now, in general,  $r_o \gg R_E$

$$\Rightarrow A_v = R_E / (r_E + R_E)$$

➤ *Two important observations:*

- $A_v \leq 1$
- *No phase shift between  $v_i$  and  $v_o$*



➤ *Current Gain:*

$$A_i = i_e/i_b = \beta + 1 \text{ (large)}$$

➤ *Input Resistance:*

$$\begin{aligned} R_i &= \frac{v_i}{i_i} = \frac{i_i r_\pi + i_o (R_E \parallel r_o)}{i_i} \\ &= \frac{i_i r_\pi + (\beta + 1) i_i (R_E \parallel r_o)}{i_i} \\ &= r_\pi + (\beta + 1)(R_E \parallel r_o) \end{aligned}$$

- If  $r_o \gg R_E$ ,  $R_i = r_\pi + (\beta + 1)R_E$

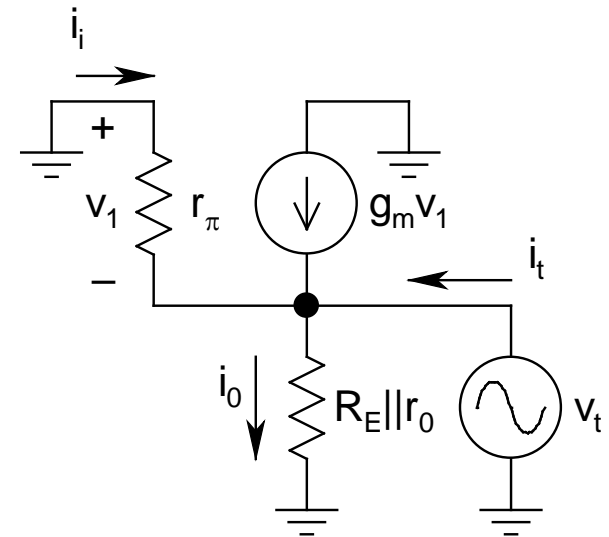
- Note that this result could have been written from *inspection* from the *ac schematic* using the technique of *Resistance Transformation*

➤ *Output Resistance:*

$$\begin{aligned} i_t &= i_0 - g_m v_1 - i_i \\ &= \frac{v_t}{R_E \parallel r_0} + g_m v_t + \frac{v_t}{r_\pi} \end{aligned}$$

$$\Rightarrow R_0 = R_E \parallel r_0 \parallel r_E \parallel r_\pi \approx r_E$$

- Note that this expression also could have been written by *inspection*

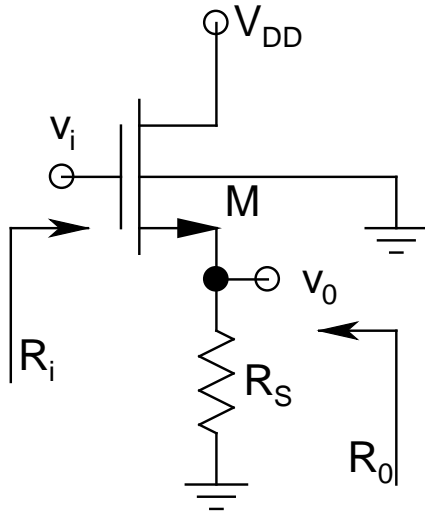


- *Output excited by a test voltage source  $v_t$ :*
  - *The current has two parallel paths: one going through the parallel combination of  $r_o$  and  $R_E$ , and the other into the emitter of  $Q$*
- The *resistance in the base lead of  $Q$  is  $r_\pi$* , which *needs to be transformed to emitter by dividing it by  $(\beta + 1) \Rightarrow$  yields  $r_E$*
- Thus,  $R_o$  becomes a parallel combination of  $r_o$ ,  $R_E$ , and  $r_E$ , which will be *typically equal to  $r_E$* , since, in general, *it's the least among the three*
- *Understand the inspection technique, it will become immensely useful to analyze circuits*

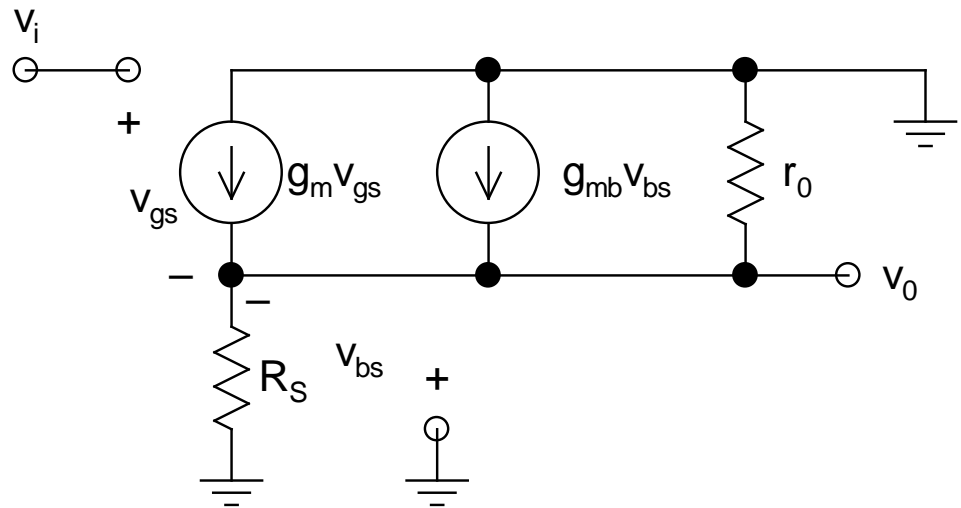
- *Some special properties of this circuit:*
  - $A_v \leq 1$  (by proper design, it can be made to approach unity very closely)
  - *Input and output in phase*
  - *Quite large input resistance*
  - *Very small output resistance*
- These properties are *highly desirable* to prevent *loading effect* of *cascaded stages* (to be discussed later)
- Thus, this stage is also known as *Buffer* or *Isolator* or *Impedance Matcher*

- **Common-Drain (CD):**

➤ Also known as *Source Follower*



**ac Schematic**



**ac Low-Frequency Equivalent**

➤ *Biasing circuit not shown*

- **Note:** *Body terminal at ground*, but *source is at a floating potential (it's the output terminal)*  
⇒ *Body effect will be very much present for M*  
⇒ *Can be avoided by putting M in its separate island* (to be discussed later)

➤ **Voltage Gain:**

- *KCL at output node:*

$$g_m v_{gs} + g_{mb} v_{bs} = v_o / (R_S \parallel r_o)$$

with  $v_{gs} = v_i - v_o$ , and  $v_{bs} = -v_o$

$$\Rightarrow A_v = \frac{v_o}{v_i} = \frac{g_m (R_S \parallel r_o)}{1 + (g_m + g_{mb})(R_S \parallel r_o)}$$